

Precision Monolithic Quad SPST Low-Voltage CMOS Analog Switches

DESCRIPTION

The DG441L, DG442L are low voltage pin-for-pin compatible companion devices to the industry standard DG441L, DG442L with improved performance.

Using BiCMOS wafer fabrication technology allows the DG441L, DG442L to operate on single and dual supplies. Single supply voltage ranges from 3 V to 12 V while dual supply operation is recommended with ± 3 V to ± 6 V.

Combining high speed (t_{ON} : 20 ns), flat $R_{DS(on)}$ over the analog signal range (5Ω), minimal insertion lose (-3 dB at 280 MHz), and excellent crosstalk and off-isolation performance (-50 dB at 50 MHz), the DG441L, DG442L are ideally suited for audio and video signal switching.

The DG441L, DG442L responds to opposite control logic as shown in the Truth Table open and two normally closed switches.

FEATURES

- Halogen-free according to IEC 61249-2-21 Definition
- 2.7 V thru 12 V single supply or ± 3 V thru ± 6 V dual supply
- On-resistance - $R_{DS(on)}$: 17 Ω
- Fast switching - t_{ON} : 20 ns
- t_{OFF} : 12 ns
- TTL, CMOS compatible
- Low leakage: 0.25 nA
- 2000 V ESD protection
- Compliant to RoHS Directive 2002/95/EC



RoHS
COMPLIANT
HALOGEN
FREE

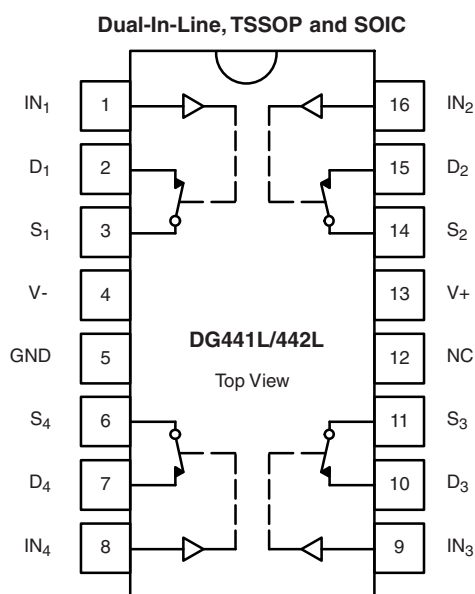
BENEFITS

- Widest dynamic range
- Low signal errors and distortion
- Break-before-make switching action
- Simple interfacing

APPLICATIONS

- Precision automatic test equipment
- Precision data acquisition
- Communication systems
- Battery powered systems
- Computer peripherals
- SDSL, DSLAM
- Audio and video signal routing

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE

Logic	DG441L	DG442L
0	On	Off
1	Off	On

Logic "0" ≤ 0.8 V
Logic "1" ≥ 2.4 V

ORDERING INFORMATION

Temp. Range	Package	Part Number
- 40 °C to 85 °C	16-pin TSSOP	DG441LDQ-T1-E3
		DG442LDQ-T1-E3
	16-pin narrow SOIC	DG441LDY-T1-E3 DG442LDY-T1-E3
- 55 °C to 125 °C	16-pin CerDIP	DG441LAK, DG441LAK/883 DG442LAK, DG442LAK/883
		DG441LAZ/883 DG442LAZ/883
	LCC-20	

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)			
Parameter	Symbol	Limit	Unit
V ₊ to V ₋		- 0.3 to 13	V
GND to V ₋ A		7	
Digital Inputs ^a V _S , V _D		GND - 0.3 to (V ₊) + 0.3 or 30 mA, whichever occurs first	
Continuous Current (any terminal)		30	mA
Current, S or D (pulsed 1 ms, 10 % duty cycle)		100	
Storage Temperature	(DQ, DY suffix)	- 65 to 125	°C
	(AK suffix)	- 65 to 150	
Power Dissipation (Packages) ^b	16-pin TSSOP ^c	450	mW
	16-pin narrow Body SOIC ^d	650	
	16-pin CerDIP ^e	900	

Notes:

- a. Signals on S_X, D_X, or IN_X exceeding V₊ or V₋ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
b. All leads welded or soldered to PC board.
c. Derate 7 mW/°C above 75 °C
d. Derate 7.6 mW/°C above 75 °C
e. Derate 12 mW/°C above 75 °C.

SPECIFICATIONS ^a (Single Supply 12 V)									
Parameter	Symbol	Test Conditions Unless Otherwise Specified V + = 12 V, V - = 0 V V _{IN} = 2.4 V, 0.8 V ^f	Temp. ^b	Typ. ^c	A Suffix Limits - 55 °C to 125 °C		D Suffix Limits - 40 °C to 85 °C		Unit
					Min. ^d	Max. ^d	Min. ^d	Max. ^d	
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full		0	12	0	12	V
Drain-Source On-Resistance	R _{DS(on)}	V + = 10.8 V, V - = 0 V I _S = 10 mA, V _D = 2/9 V	Room Full	20		30 45		30 40	Ω
On-Resistance Match Between Channels ^e	ΔR _{DS(on)}	I _S = 10 mA, V _D = 9 V	Room	0.1		0.5		0.5	
Switch Off Leakage Current	I _{S(off)}	V _D = 1/11 V, V _S = 11/1 V	Room Full		- 1 - 15	1 15	- 1 - 10	1 10	nA
	I _{D(off)}		Room Full		- 1 - 15	1 15	- 1 - 10	1 10	
Channel On Leakage Current	I _{D(on)}	V _S = V _D = 11/1 V	Room Full		- 1 - 15	1 15	- 1 - 10	1 10	
Digital Control									
Input Current, V _{IN} Low	I _{IL}	V _{IN} Under Test = 0.8 V	Full	0.01	- 1.5	1.5	- 1	1	μA
Input Current, V _{IN} High	I _{IH}	V _{IN} Under Test = 2.4 V	Full		- 1.5	1.5	- 1	1	
Dynamic Characteristics									
Turn-On Time	t _{ON}	R _L = 300 Ω, C _L = 35 pF V _S = 5 V, see figure 2	Room Full	20		60 80		60 70	ns
Turn-Off Time	t _{OFF}		Room Full	12		35 50		35 45	
Charge Injection ^e	Q	V _g = 0 V, R _g = 0 Ω, C _L = 10 nF	Room	5					pC
Off Isolation ^e	OIRR	R _L = 50 Ω, C _L = 5 pF , f = 1 MHz	Room	71					dB
Channel-to-Channel Crosstalk ^e	X _{TALK}		Room	95					
Source Off Capacitance ^e	C _{S(off)}	f = 1 MHz	Room	5					pF
Drain Off Capacitance ^e	C _{D(off)}		Room	6					
Channel On Capacitance ^e	C _{D(on)}		Room	15					
Power Supplies									
Positive Supply Current	I+	V _{IN} = 0 V or 12 V	Full	0.03		1.5		1	μA
Negative Supply Current	I-		Room Full	- 0.002	- 1 - 7.5		- 1 - 5		
Ground Current	I _{GND}		Full	- 0.002	- 1.5		- 1		



SPECIFICATIONS ^a (Dual Supply ± 5 V)									
Parameter	Symbol	Test Conditions Unless Otherwise Specified V + = 5 V, V - = - 5 V V _{IN} = 2.4 V, 0.8 V ⁱ	Temp. ^b	Typ. ^c	A Suffix Limits - 55 °C to 125 °C		D Suffix Limits - 40 °C to 85 °C		Unit
					Min. ^d	Max. ^d	Min. ^d	Max. ^d	
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full		- 5	5	- 5	5	V
Drain-Source On-Resistance	R _{DS(on)}	V + = 5 V, V - = - 5 V I _S = 10 mA, V _D = ± 3.5 V	Room Full	20		33 45		33 40	Ω
On-Resistance Match Between Channels ^e	ΔR _{DS(on)}	I _S = 10 mA, V _D = ± 3.5 V	Room	0.1		0.5		0.5	
Switch Off Leakage Current ^g	I _{S(off)}	V + = 5.5 , V - = - 5.5 V V _D = ± 4.5 V, V _S = ± 4.5 V	Room Full		- 1 - 15	1 15	- 1 - 10	1 10	nA
	I _{D(off)}		Room Full		- 1 - 15	1 15	- 1 - 10	1 10	
Channel On Leakage Current ^g	I _{D(on)}	V + = 5.5 V, V - = - 5.5 V V _S = V _D = ± 4.5 V	Room Full		- 1 - 15	1 15	- 1 - 10	1 10	
Digital Control									
Input Current, V _{IN} Low ^e	I _{IL}	V _{IN} Under Test = 0.8 V	Full	0.05	- 1.5	1.5	- 1	1	μA
Input Current, V _{IN} High ^e	I _{IH}	V _{IN} Under Test = 2.4 V	Full	0.05	- 1.5	1.5	- 1	1	
Dynamic Characteristics									
Turn-On Time	t _{ON}	R _L = 300 Ω, C _L = 35 pF V _S = ± 3.5 V, see figure 2	Room Full	21		60 83		60 70	ns
Turn-Off Time	t _{OFF}		Room Full	16		35 55		35 45	
Charge Injection ^e	Q	V _g = 0 V, R _g = 0 Ω, C _L = 10 nF	Room	5					pC
Off Isolation ^e	OIRR	R _L = 50 Ω, C _L = 5 pF , f = 1 MHz	Room	68					dB
Channel-to-Channel Crosstalk ^e	X _{TALK}		Room	85					
Source Off Capacitance ^e	C _{S(off)}	f = 1 MHz	Room	9					pF
Drain Off Capacitance ^e	C _{D(off)}		Room	9					
Channel On Capacitance ^e	C _{D(on)}		Room	20					
Power Supplies									
Positive Supply Current ^e	I ₊	V _{IN} = 0 V or 5 V	Full	0.002		1.5		1	μA
Negative Supply Current ^e	-		Room Full	- 0.002	- 1 - 7.5		- 1 - 5		
Ground Current ^e	I _{GND}		Full	- 0.002	- 1.5		- 1		

SPECIFICATIONS ^a (Single Supply 5 V)									
Parameter	Symbol	Test Conditions Unless Otherwise Specified V + = 5 V, V - = 0 V V _{IN} = 2.4 V, 0.8 V ^f	Temp. ^b	Typ. ^c	A Suffix Limits - 55 °C to 125 °C		D Suffix Limits - 40 °C to 85 °C		Unit
					Min. ^d	Max. ^d	Min. ^d	Max. ^d	
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full			5		5	V
Drain-Source On-Resistance ^e	R _{DS(on)}	V + = 4.5 V I _S = 5 mA, V _D = 1 V, 3.5 V	Room Full	35		50 88		50 75	Ω
On-Resistance Match Between Channels ^e	ΔR _{DS(on)}	I _S = 10 mA, V _D = 3.5 V	Room	0.5		1		1	
Dynamic Characteristics									
Turn-On Time ^e	t _{ON}	R _L = 300 Ω, C _L = 35 pF V _S = 3.5 V, see figure 2	Room Hot	27		50 90		50 60	ns
Turn-Off Time ^e	t _{OFF}		Room Hot	15		30 55		30 40	
Charge Injection ^e	Q	V _g = 0 V, R _g = 0 Ω, C _L = 10 nF	Room	0.5					pC
Power Supplies									
Positive Supply Current ^e	I +	V _{IN} = 0 V or 5 V	Full	10		200		100	μA
Negative Supply Current ^e	I -		Room Full	- 0.002	- 1 - 7.5		- 1 - 5		
Ground Current ^e	I _{GND}		Full	- 10	- 200		- 100		



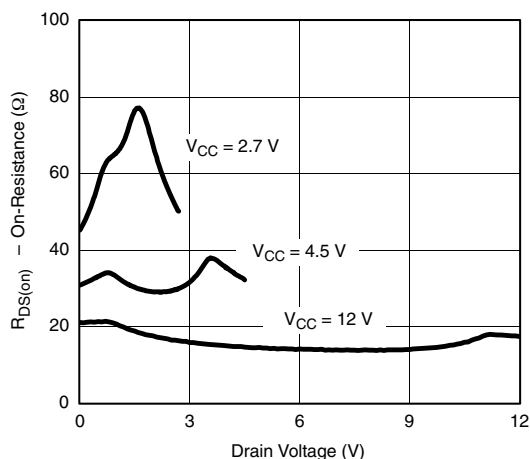
SPECIFICATIONS ^a (Single Supply 3 V)									
Parameter	Symbol	Test Conditions Unless Otherwise Specified V + = 3 V, V - = 0 V V _{IN} = 0.4 V ^f	Temp. ^b	Typ. ^c	A Suffix Limits - 55 °C to 125 °C		D Suffix Limits - 40 °C to 85 °C		Unit
					Min. ^d	Max. ^d	Min. ^d	Max. ^d	
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full		0	3	0	3	V
Drain-Source On-Resistance	R _{DS(on)}	V + = 2.7 V, V - = 0 V I _S = 5 mA, V _D = 0.5, 2.2 V	Room Full	65		80 115		80 100	Ω
On-Resistance Match Between Channels ^e	ΔR _{DS(on)}	I _S = 5 mA, V _D = 2.2 V	Room	1		3		3	
Switch Off Leakage Current ^g	I _{S(off)}	V + = 3.3 , V - = 0 V V _D = 1, 2 V, V _S = 2, 1 V	Room Full		- 1 - 15	1 15	- 1 - 10	1 10	nA
	I _{D(off)}		Room Full		- 1 - 15	1 15	- 1 - 10	1 10	
Channel On Leakage Current ^g	I _{D(on)}	V + = 3.3 V, V - = 0 V V _S = V _D = 1, 2 V	Room Full		- 1 - 15	1 15	- 1 - 10	1 10	
Digital Control									
Input Current, V _{IN} Low ^e	I _{IL}	V _{IN} under test = 0.4 V	Full	0.005	- 1.5	1.5	- 1	1	μA
Input Current, V _{IN} High ^e	I _{IH}	V _{IN} under test = 2.4 V	Full	0.005	- 1.5	1.5	- 1	1	
Dynamic Characteristics									
Turn-On Time	t _{ON}	R _L = 300 Ω, C _L = 35 pF V _S = 1.5 V, see figure 2	Room Full	50		136 175		136 151	ns
Turn-Off Time	t _{OFF}		Room Full	30		100 140		100 125	
Charge Injection ^e	Q	V _g = 0 V, R _g = 0 Ω, C _L = 10 nF	Room	1					pC
Off Isolation ^e	OIRR	R _L = 50 Ω, C _L = 5 pF , f = 1 MHz	Room	68					dB
Channel-to-Channel Crosstalk ^e	X _{TALK}		Room	85					
Source Off Capacitance ^e	C _{S(off)}	f = 1 MHz	Room	6					pF
Drain Off Capacitance ^e	C _{D(off)}		Room	6					
Channel On Capacitance ^e	C _{D(on)}		Room	20					

Notes:

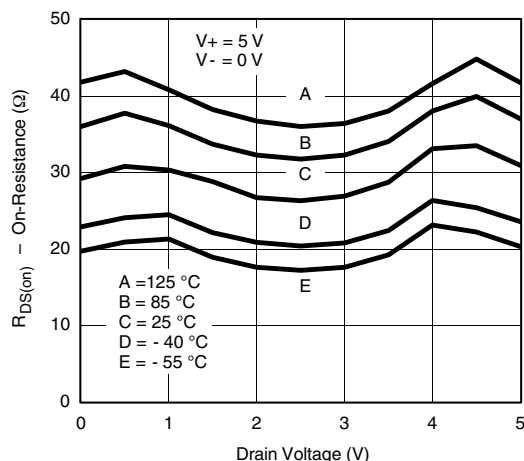
- Refer to PROCESS OPTION FLOWCHART.
- Room = 25 °C, Full = as determined by the operating temperature suffix.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
- Guaranteed by design, not subject to production test.
- V_{IN} = input voltage to perform proper function.
- Leakage parameters are guaranteed by worst case test conditions and not subject to test.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

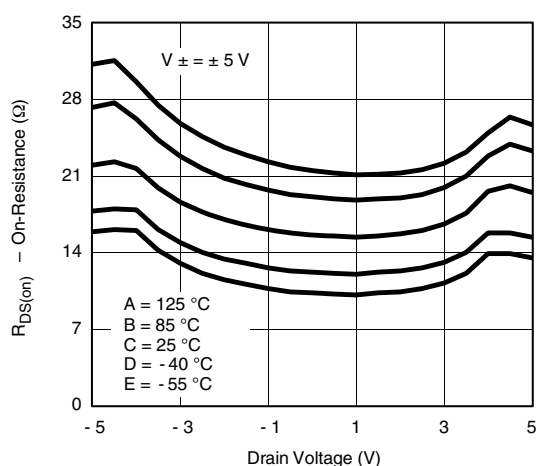
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



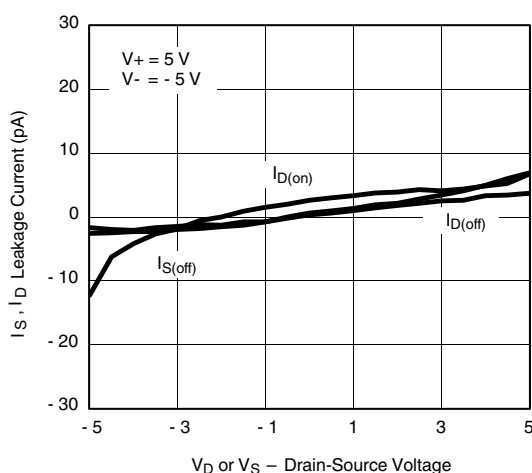
**$R_{DS(on)}$ vs. Drain Voltage
(Single Supply)**



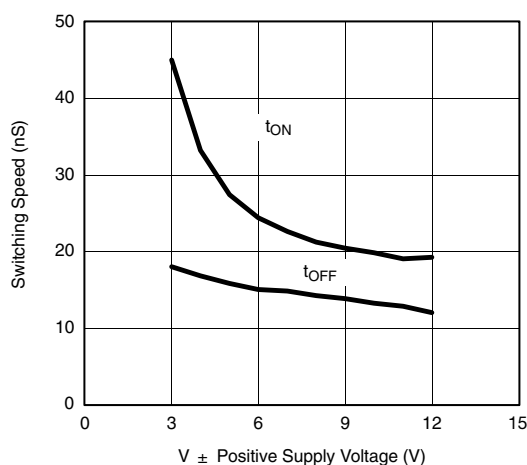
**$R_{DS(on)}$ vs. Drain Voltage and Temperature
(Single Supply)**



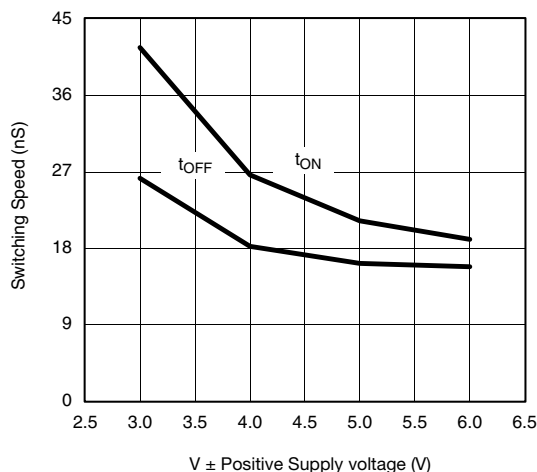
**$R_{DS(on)}$ vs. Drain Voltage and Temperature
(Dual Supply)**



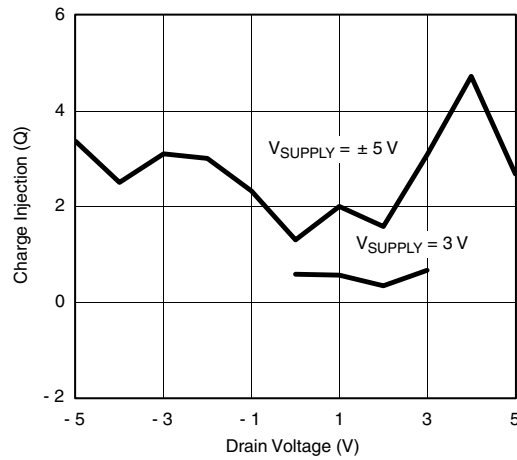
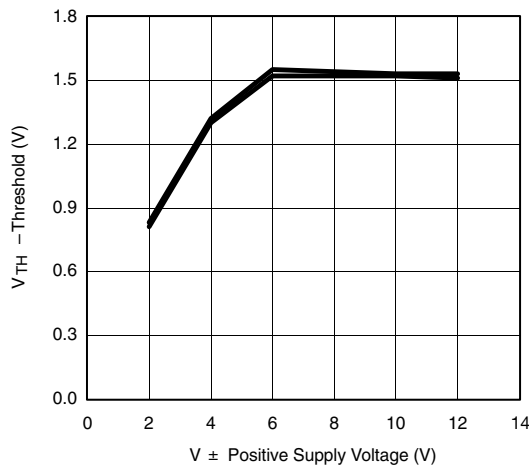
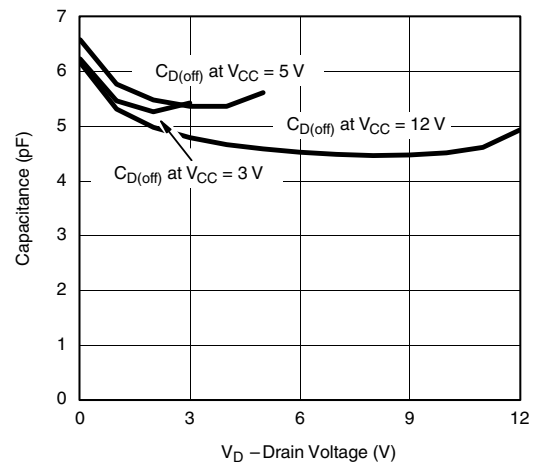
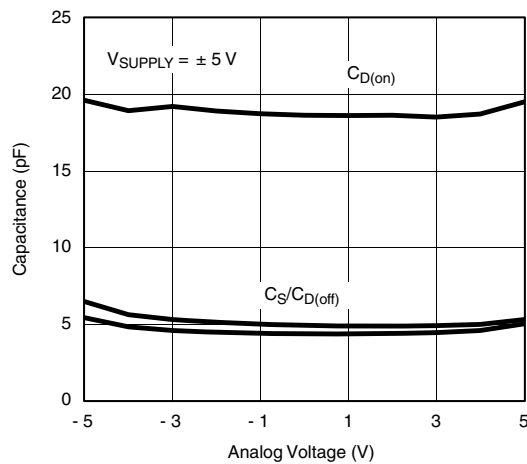
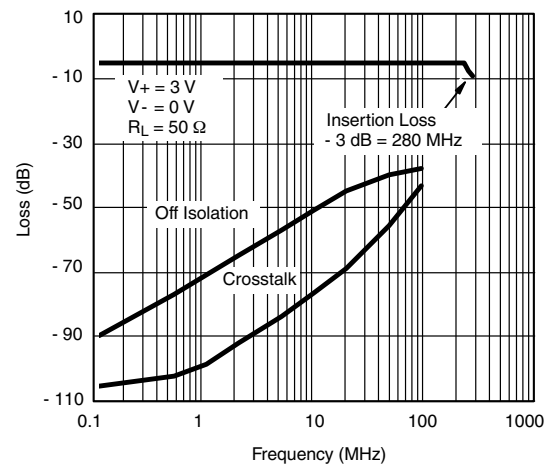
**Leakage Current vs. Analog Voltage
(Dual Supply)**



Switching Time vs. Single Supply



Switching Time vs. Dual Supply

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

Charge Injection vs. Drain Voltage

Input Threshold vs. Single Supply Voltage

Drain Capacitance vs. Drain Voltage (Single Supply)

Capacitance vs. Analog Signal (Dual Supply)

Insertion Loss, Off Isolation and Crosstalk vs. Frequency (Single Supply)

SCHEMATIC DIAGRAM (TYPICAL CHANNEL)

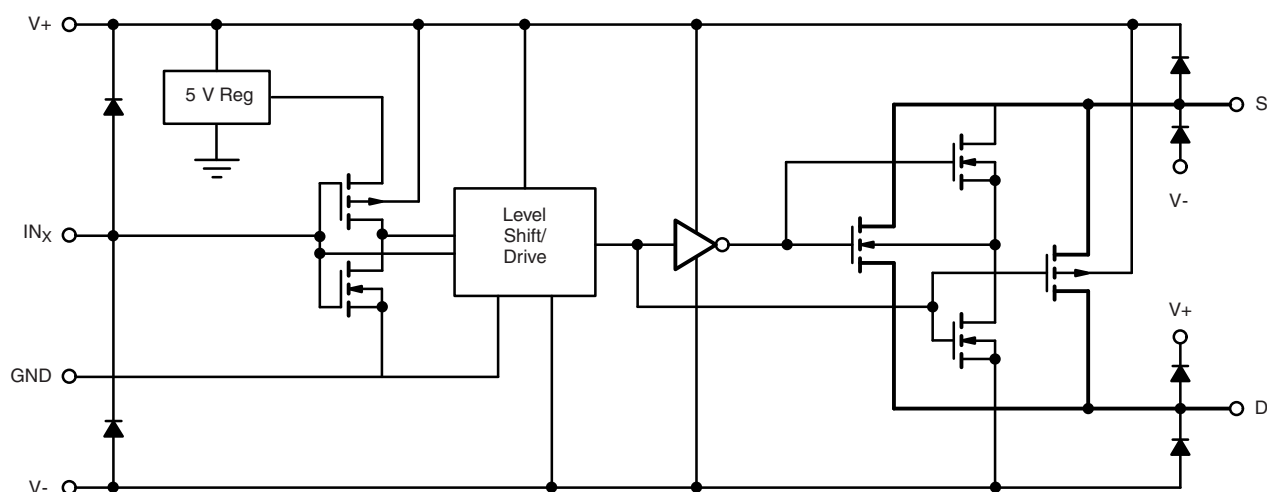
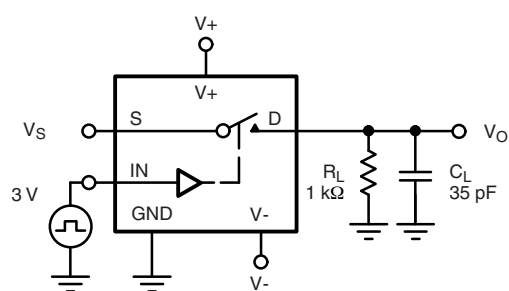
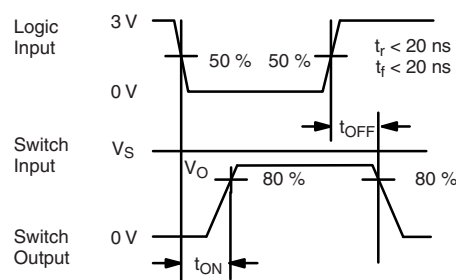


Figure 1.

TEST CIRCUITS



C_L (includes fixture and stray capacitance)



Note: Logic input waveform is inverted for DG442.

Figure 2. Switching Time

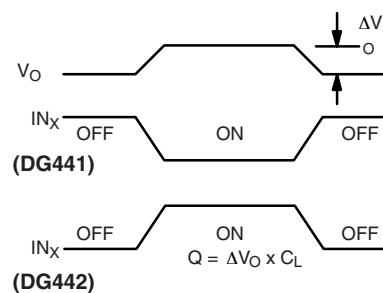
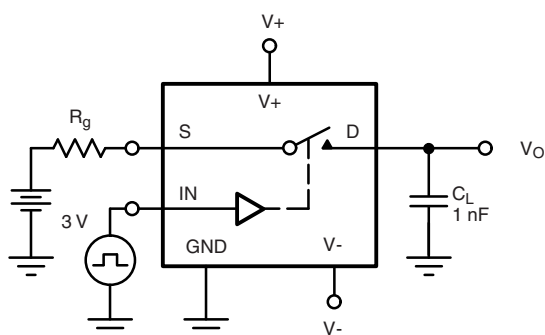
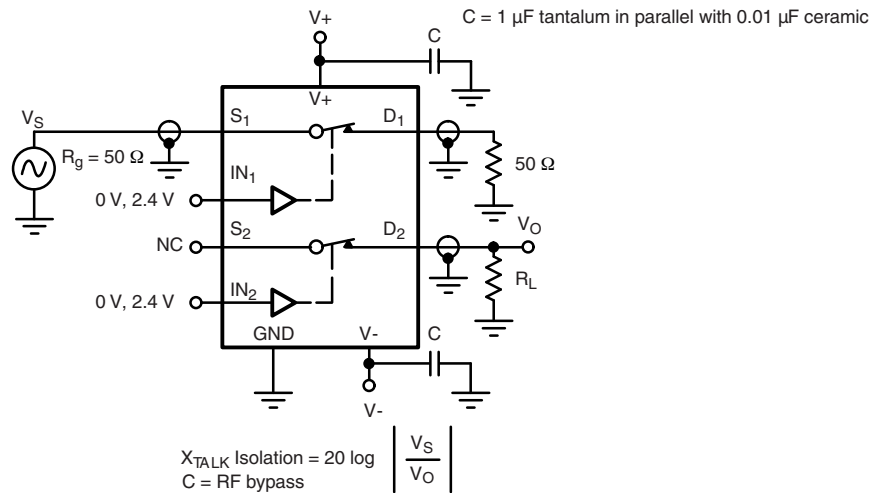
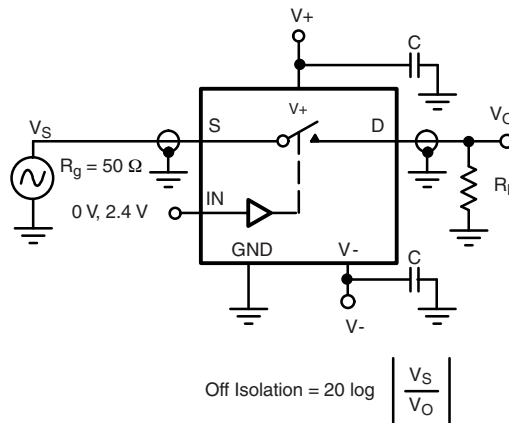
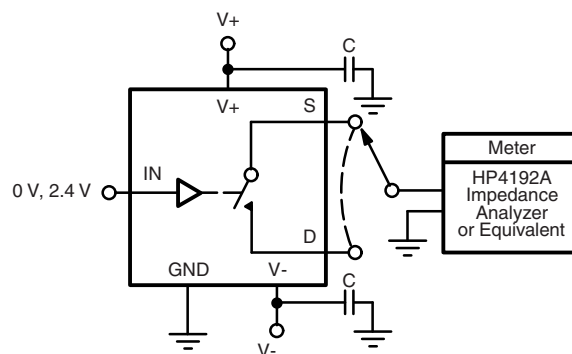


Figure 3. Charge Injection

TEST CIRCUITS

Figure 4. Crosstalk

Figure 5. Off Isolation

Figure 6. Source/Drain Capacitances

APPLICATIONS

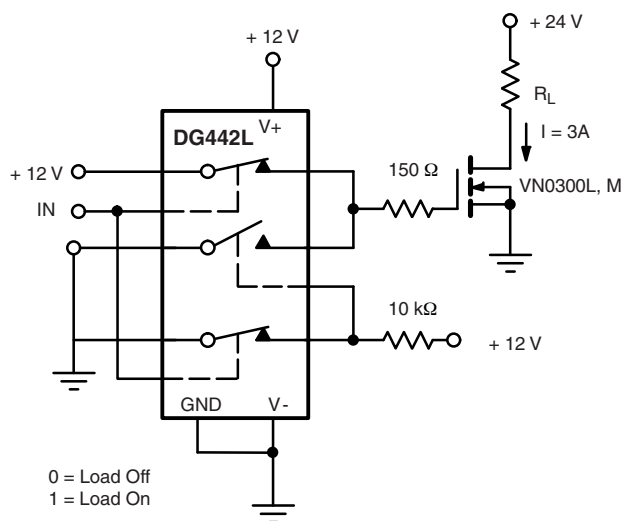


Figure 7. Power MOSFET Driver

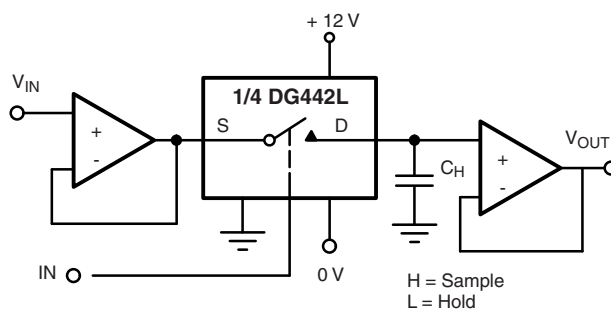


Figure 8. Open Loop Sample-and-Hold

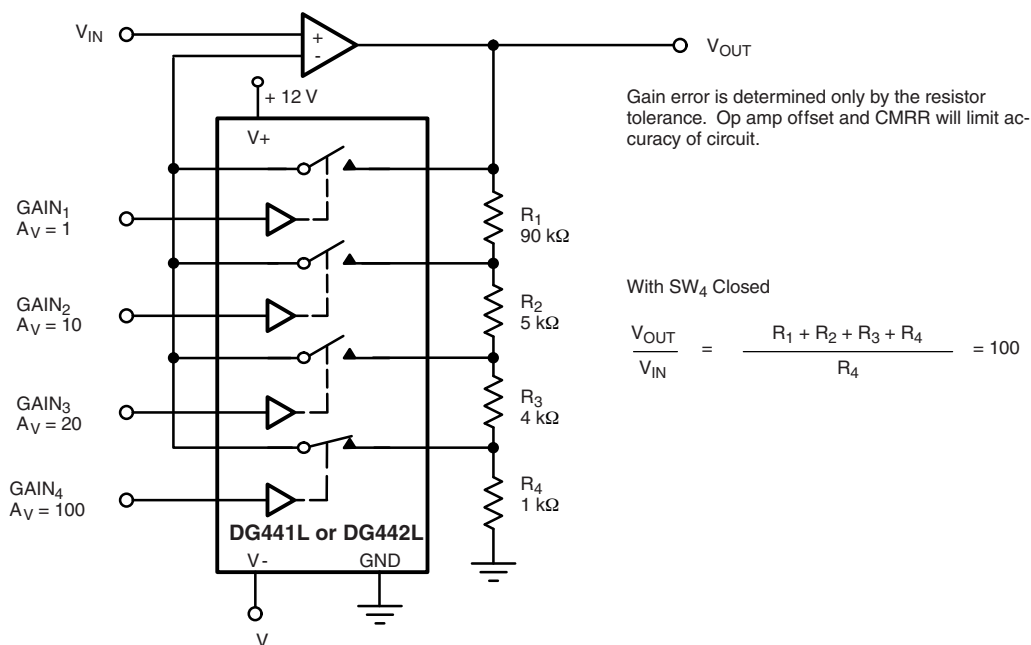


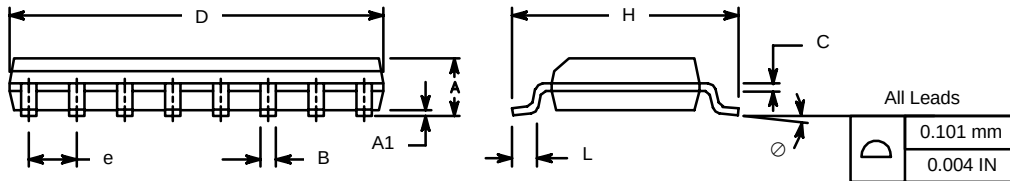
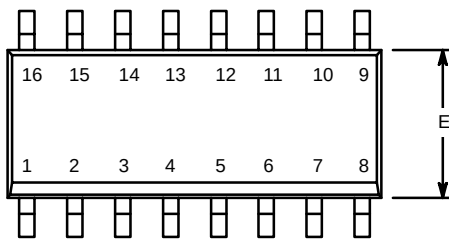
Figure 9. Precision-Weighted Resistor Programmable-Gain Amplifier

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71399.



SOIC (NARROW): 16-LEAD

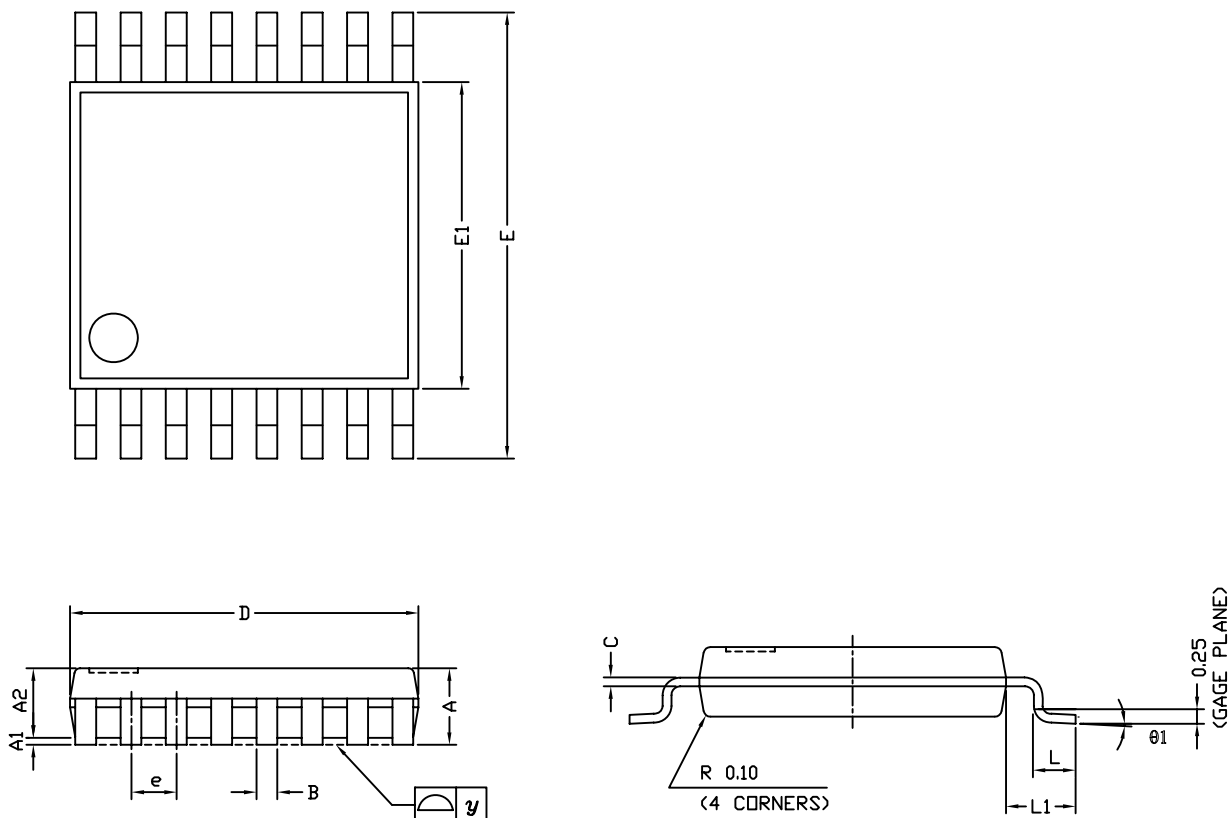
JEDEC Part Number: MS-012



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A ₁	0.10	0.20	0.004	0.008
B	0.38	0.51	0.015	0.020
C	0.18	0.23	0.007	0.009
D	9.80	10.00	0.385	0.393
E	3.80	4.00	0.149	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
L	0.50	0.93	0.020	0.037
Ø	0°	8°	0°	8°

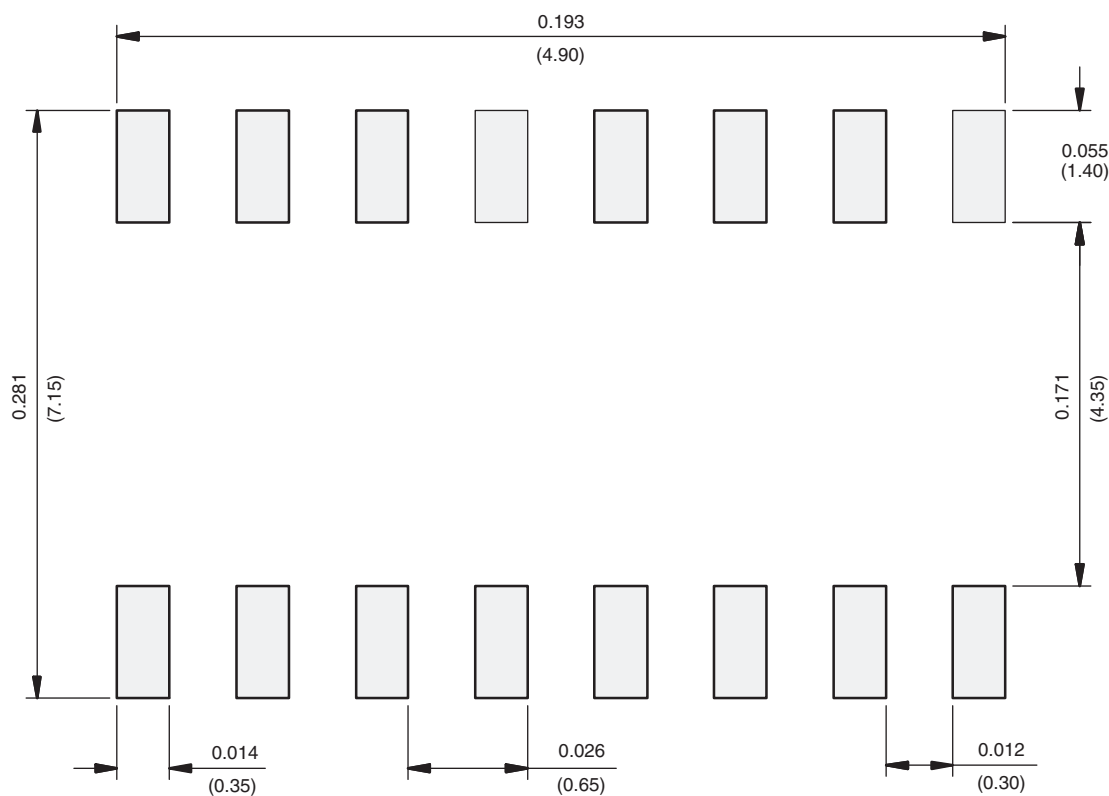
ECN: S-03946—Rev. F, 09-Jul-01
DWG: 5300

TSSOP: 16-LEAD



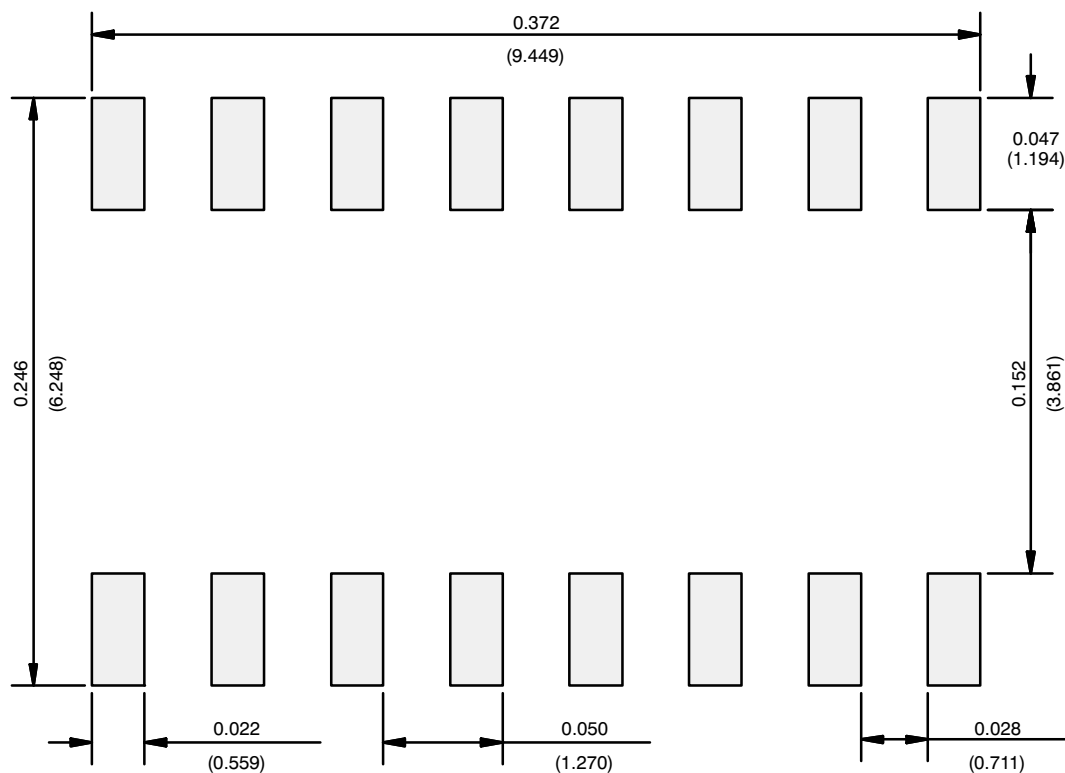
Symbols	DIMENSIONS IN MILLIMETERS		
	Min	Nom	Max
A	-	1.10	1.20
A1	0.05	0.10	0.15
A2	-	1.00	1.05
B	0.22	0.28	0.38
C	-	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
e	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
y	-	-	0.10
θ1	0°	3°	6°
ECN: S-61920-Rev. D, 23-Oct-06			
DWG: 5624			

RECOMMENDED MINIMUM PAD FOR TSSOP-16



Recommended Minimum Pads
Dimensions in inches (mm)

RECOMMENDED MINIMUM PADS FOR SO-16



Recommended Minimum Pads
Dimensions in Inches/(mm)

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Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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